







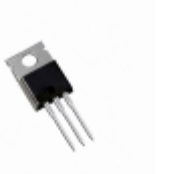

	IRFB31N20DPBF	
	Hersteller-Teilenummer:	IRFB31N20DPBF
	Hersteller / Marke:	International Rectifier (Infineon Technologies)
	Teil der Beschreibung:	MOSFET N-CH 200V 31A TO-220AB
	Datenblätter:	 IRFB31N20DPBF.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 6163 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	IRFB31N20DPBF
Hersteller	International Rectifier (Infineon Technologies)
Beschreibung	MOSFET N-CH 200V 31A TO-220AB
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	6163 pcs Stock
Serie	HEXFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Verlustleistung (max)	3.1W (Ta), 200W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	31A (Tc)
Rds On (Max) @ Id, Vgs	82 mOhm @ 18A, 10V
VGS (th) (Max) @ Id	5.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	107nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2370pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube

























IRFB31N20DPBF ist neu im Original, Suche IRFB31N20DPBF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IRFB31N20DPBF International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IRFB31N20DPBF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>IRFB3206GPBF International Rectifier (Infineon Technologies) MOSFET N-CH 60V 120A TO220AB</p>	 <p>IRFB3077PBF International Rectifier (Infineon Technologies) MOSFET N-CH 75V 120A TO-220AB</p>	 <p>IRFB3077GPBF International Rectifier (Infineon Technologies) MOSFET N-CH 75V 120A TO-220AB</p>	 <p>IRFB3206G IR IRFB3206G IR</p>
 <p>IRFB3207 IR IRFB3207 IR</p>	 <p>IRFB3077GPBF. IR IRFB3077GPBF. IR</p>	 <p>IRFB3206PBF International Rectifier (Infineon Technologies) MOSFET N-CH 60V 120A TO-220AB</p>	 <p>IRFB31N20D IR IRFB31N20D IR</p>

heiße Teile

Mehr

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|---|---|---|--|---|
|  IRFB17N50LPBF |  IRFB17N60K |  IRFB17N60K |  IRFB17N60KPBF |  IRFB17N60KPBF |
|  IRFB18N50K |  IRFB18N50K |  IRFB20N50K |  IRFB20N50KPBF |  IRFB20N50KPBF |
|  IRFB23N15D |  IRFB23N15DPBF |  IRFB23N20D |  IRFB23N20DPBF |  IRFB260N |
|  IRFB260NPBF |  IRFB3004 |  IRFB3004G |  IRFB3006 |  IRFB3006PBF. |
|  IRFB3077 |  IRFB3077GPBF |  IRFB3077GPBF. |  IRFB3077PBF |  IRFB31N20D |
|  IRFB3206 |  IRFB3206G |  IRFB3206GPBF |  IRFB3206PBF |  IRFB3207 |
|  IRFB3207PBF |  IRFB3207ZG |  IRFB3207ZPBF |  IRFB3256PBF |  IRFB3306 |
|  IRFB3306G |  IRFB3306GPBF |  IRFB3306PBF |  IRFB3307 |  IRFB3307G |
|  IRFB3307PBF |  IRFB3307ZG |  IRFB3307ZGPBF |  IRFB3307ZPBF |  IRFB3307ZPBF. |
|  IRFB33N15D |  IRFB3407Z |  IRFB3415 |  IRFB3507PBF |  IRFB3607 |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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